FORM PTO-1449 LIST OF PATENTS AND APPLICANT'S INFORMATION DISCLOSURE STATEMENT

ATTORNEY DOCKET NO .: 99CT22053527

SERIAL NO.: Not Yet Assigned

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FILING DATE: Herewith

APPLICANT: COFFA ET AL.

GROUP:

REFERENCE DESIGNATION U.S. PATENT DOCUMENTS							
EXAMINER INITIALS		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING IF APPROPRIATE
Par	AA	5,045,498	9/3/91	WANG ET AL.	437	129	+
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П	FOREIGN PATENT DOCUMENTS							
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		OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)				
$\Gamma$	AP	Patent Abstract of Japan Publication No. 01074783. Publication Date: 3/20/89. Inventor: Ogita Shoichi "Semiconductor Light-Emitting Device."				
H	AQ	Document No. XP002129644. Franzo, et al. "Mechanism and Performance of Forward and Reverse Blas Electroluminescence at 1.54 µm From Er-doped Si Diodes" March 1997. pp.				
H	$\rightarrow$	2784-2793.  Document No. XP002129645. Coffa, et al. "Direct Evidence of Impact Excitation and Document No. XP002129645. The Light Emitting Si Diodes" July 1998. pp. 93-95.				
1	- AR	Document No. XP002129645. Coffa, et al. "Direct Evidence of Impact Burnel." Spatial Profiling of Excited Er in Light Emitting Si Diodes" July 1998. pp. 93-95.				
	AS					

EXAMINER: Laughes Will 25 oct 01 DATE CONSIDERED:

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609;
\* Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.